



2SB1269/2SD1905

High-Current Switching Applications

Applications

- Suitable for relay drivers, high-speed inverters, converters, and other general high-current switching applications.

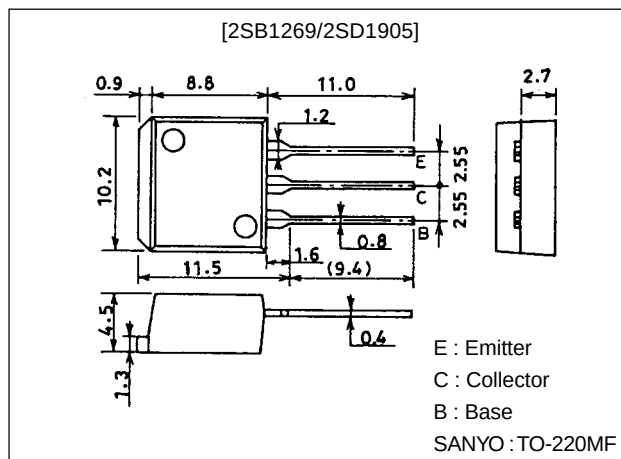
Features

- Suitable for sets whose height is restricted.
- Low collector to emitter saturation voltage.
- Wide ASO and highly resistant to breakdown.

Package Dimensions

unit:mm

2049B



() : 2SB1269

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)7	A
Collector Current (Pulse)	I_{CP}		(-)12	A
Collector Dissipation	P_C		1.65	W
		$T_c=25^\circ\text{C}$	40	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0$			(-)0.1	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)0.1	mA
DC Current Gain	h_{FE1}	$V_{CE}=(-)2\text{V}, I_C=(-)1\text{A}$	70*		280*	
	h_{FE2}	$V_{CE}=(-)2\text{V}, I_C=(-)5\text{A}$	30			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)5\text{V}, I_C=(-)1\text{A}$		10		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)4\text{A}, I_B=(-)0.4\text{A}$			(-)0.4	V

* : The 2SB1269/2SD1905 are classified by 1A h_{FE} as follows :

70	Q	140	100	R	200	140	S	280
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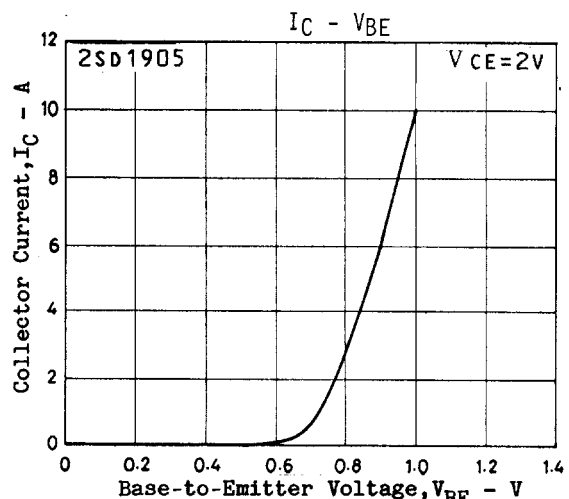
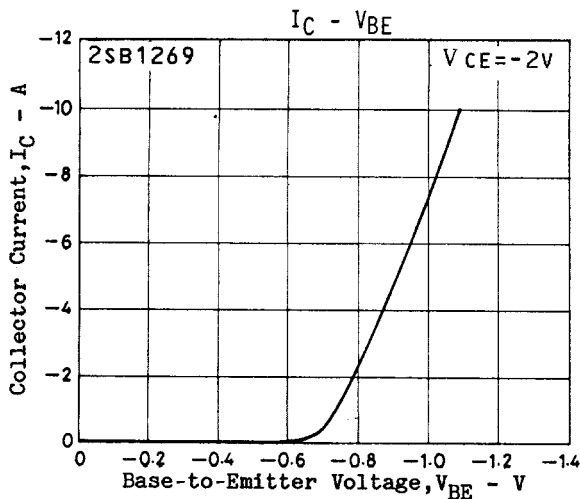
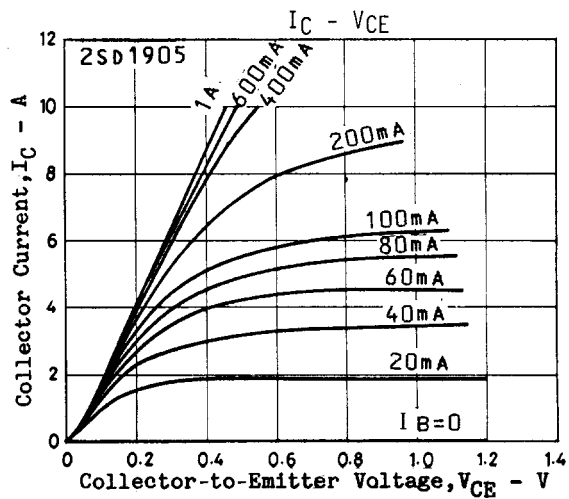
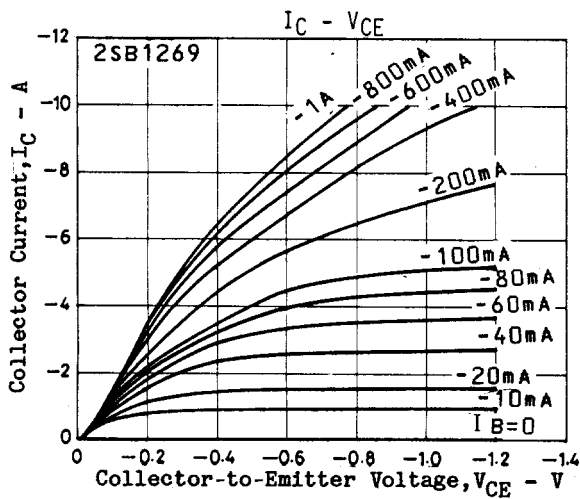
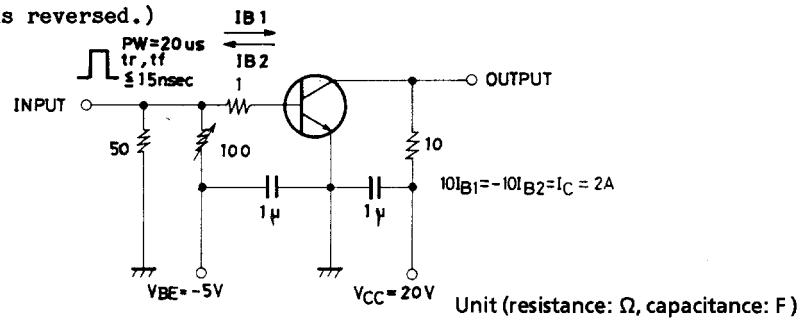
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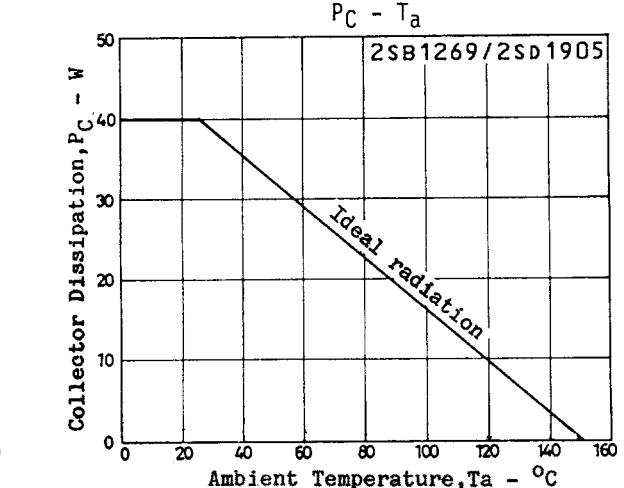
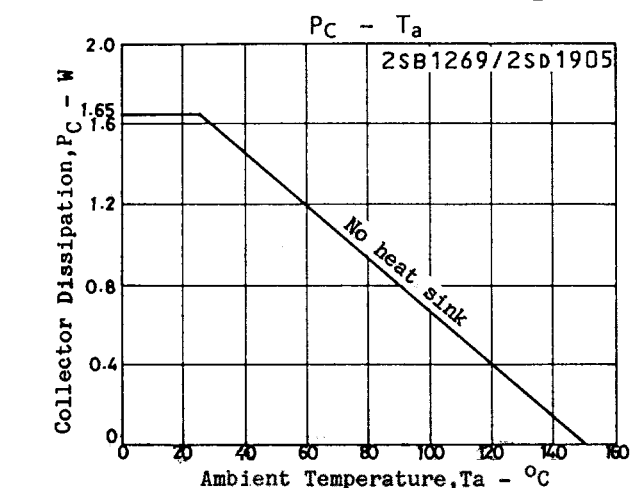
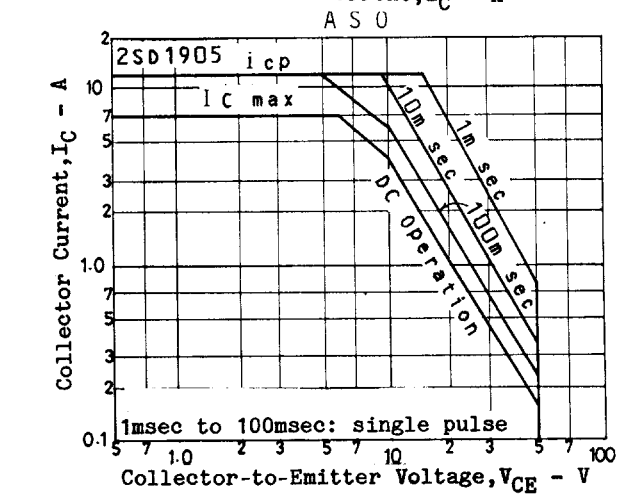
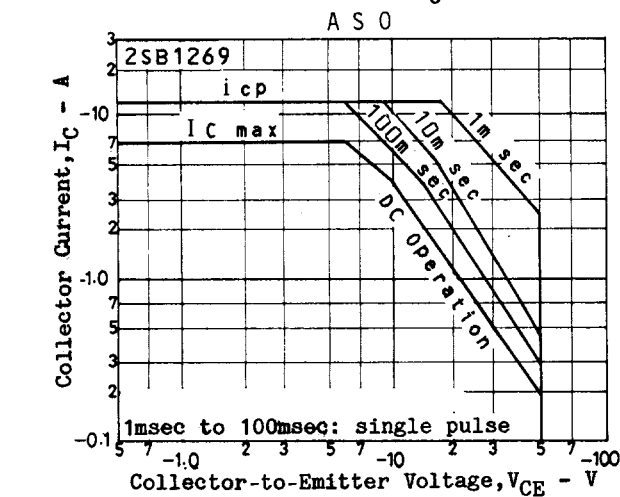
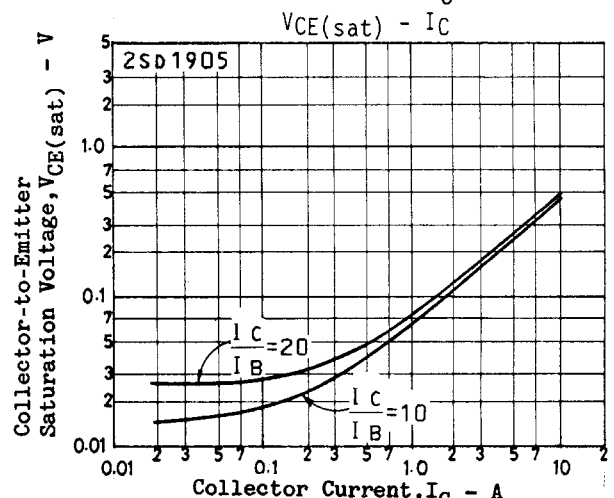
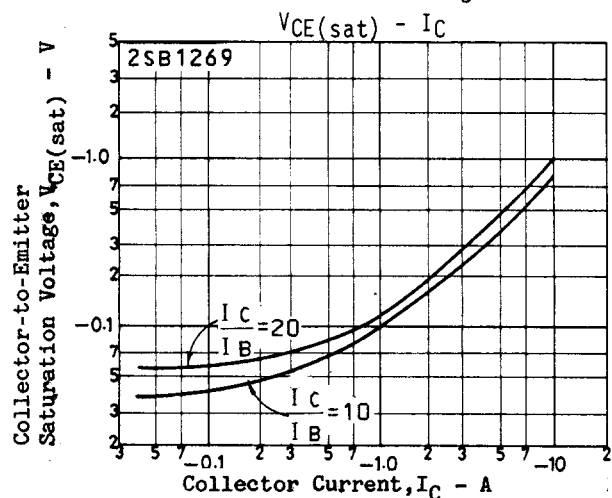
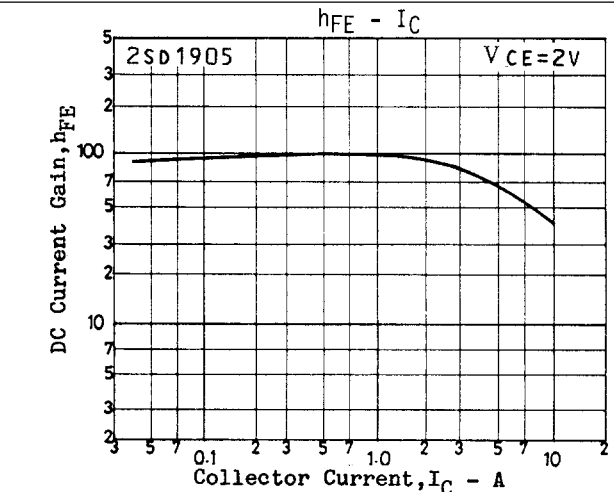
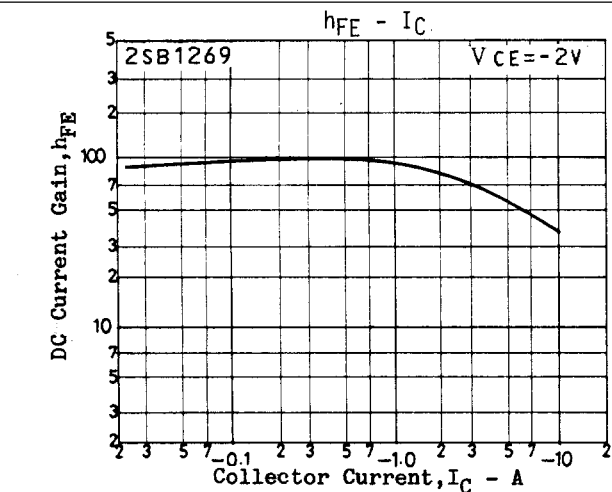
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)1mA, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)1mA, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified test circuit.		0.2		μs
Storage Time	t_{stg}	See specified test circuit.		(0.1)		μs
Fall Time	t_f	See specified test circuit.		0.3		μs
				(0.7)		μs
				0.9		μs

Switching Time Test Circuit

(For PNP, the polarity is reversed.)



2SB1269/2SD1905



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